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SM74611

SNVS903A - DECEMBER 2012 - REVISED MARCH 2015

SM74611 Smart Bypass Diode

Technical

Documents

1 Features

- Maximum reverse voltage (V_R) of 30 V
- Operating forward current (I_F) of up to 15 A
- Low average forward voltage (26 mV at 8 A)
- · Less power dissipation than Schottky diode
- Lower leakage current than Schottky diode
- Footprint and pin compatible with conventional D2PAK Schottky diode
- Operating range (Tj) of -40°C to 125°C

2 Applications

- Bypass Diodes for Photovoltaic Panels
- Bypass Diodes for Microinverter and Power Optimizer

3 Description

The SM74611 is a smart bypass diode used in photovoltaic applications. It serves the purpose of providing an alternate path for string current when parts of the panel are shaded during normal operation. Without bypass diodes, the shaded cells will exhibit a hot spot which is caused by excessive power dissipation in the reverse biased cells.

Currently, conventional P-N junction diodes or Schottky diodes are used to mitigate this issue. Unfortunately the forward voltage drop for these diodes is still considered high (~0.6 V for normal diodes and 0.4 V for Schottky). With 10 A of currents flowing through these diodes, the power dissipation can reach as high as 6 W. This in turn will raise the temperature inside the junction box where these diodes normally reside and reduce module reliability.

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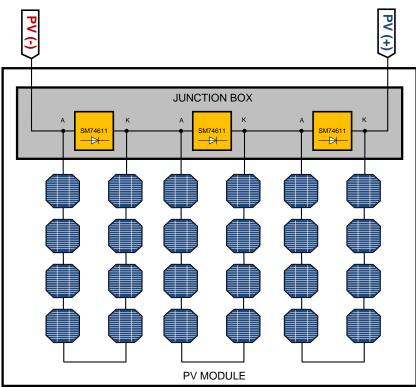
Software

The advantage of the SM74611 is that it has a lower forward voltage drop than P-N junction and Schottky diodes. It has a typical average forward voltage drop of 26 mV at 8A of current. This translates into typical power dissipation of 208 mW, which is significantly lower than the 3.2 W of conventional Schottky diodes. The SM74611 is also footprint and pin compatible with conventional D2PAK Schottky diodes, making it a drop-in replacement in many applications.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)							
SM74611	DDPAK/TO-263 (KTT) (3)	10.16 mm x 9.02 mm							

(1) For all available packages, see the orderable addendum at the end of the datasheet.



Typical Application in a Junction Box

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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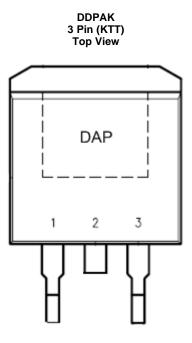
4 Revision History

Cł	nanges from Original (December 2012) to Revision A	Page
•	Added new junction temperature for t ≤ 1 hour	4
•	Added Thermal Table	4
•	Changed typical characteristic curves	5



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5 Pin Configuration and Functions



Pin Functions

PIN I/O		1/0	DESCRIPTION
		1/0	DESCRIPTION
ANODE	1,3 ⁽¹⁾	Ι	Connect both of these pins to the negative side of the PV cells
CATHODE	2,DAP ⁽²⁾	0	Pin 2 and the DAP are shorted internally. Connect the DAP to the positive side of the PV cells

(1) Pin 1 and Pin 3 should be connected together for proper operation

(2) Package drawing at the end of datasheet is shown without Pin 2 being trimmed

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ^{(1) (2)}

	MIN	MAX	UNIT
Ambient Storage temperature, T _{stg}	-65	125	°C
DC Reverse Voltage		30	V
Forward Current		24	А
Junction Temperature, t ≤ 1 hour		135	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) System must be thermally managed so as not to exceed maximum junction temperature

6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1000	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 $^{\left(2\right) }$	±250	V

 JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±XXX V may actually have higher performance.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as ±YYY V may actually have higher performance.

6.3 Recommended Operating Conditions ⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM MAX	UNIT
DC Reverse Voltage		28	V
Junction Temperature Range (T _J)	-40	125	°C
Forward Current	0	15	А

(1) System must be thermally managed so as not to exceed maximum junction temperature

6.4 Thermal Information

		SM74611	
	THERMAL METRIC ⁽¹⁾	DDPAK (KTT)	UNIT
		3 PINS	
R_{\thetaJA}	Junction-to-ambient thermal resistance	40.4	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	42.6	
$R_{\theta JB}$	Junction-to-board thermal resistance	23.0	°C/W
ΨJT	Junction-to-top characterization parameter	9.8	°C/w
Ψ _{JB}	Junction-to-board characterization parameter	22.0	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	0.5	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

6.5 Electrical Characteristics

	PARAMETER	TEST COND	MIN	TYP	MAX	UNIT	
I _{F(AVG)}	Forward Current				8	15	А
V _{F(AVG)}	Forward Voltage	I _F = 8A	$T_J = 25^{\circ}C$		26		mV

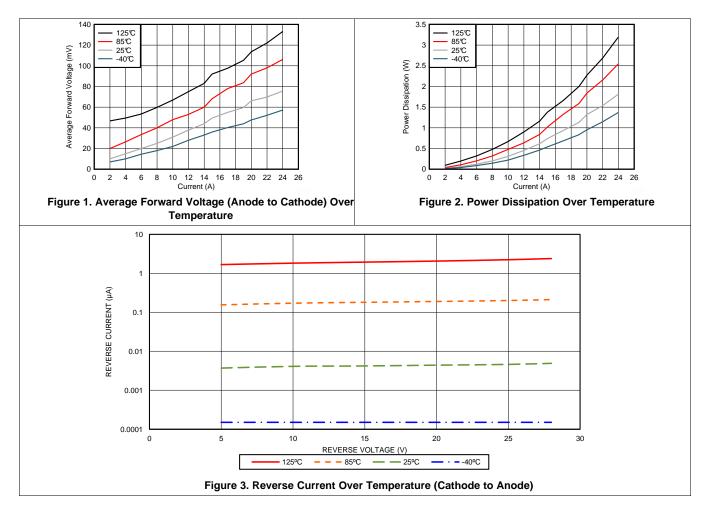


Electrical Characteristics (continued)

	PARAMETER	TEST CO	NDITIONS	MIN TYP	MAX	UNIT
P _D	Power Dissipation		$T_J = 25^{\circ}C$	208		
		I _F = 8A	$T_J = 125^{\circ}C$	450		
		T _F = Or t	-40°C to 125°C	5°C 575		mW
		1 454	$T_J = 25^{\circ}C$	695		
		I _F = 15A	T _J = 125°C	1389		
D	Duty Cycle	1 84	$T_J = 25^{\circ}C$	99.5%		
		$I_F = 8A$	$T_J = 125^{\circ}C$	96.0%		
I _R	Reverse Leakage Current	1/ 201/	$T_J = 25^{\circ}C$	0.3		
		V _{REVERSE} = 28V	$T_J = 125^{\circ}C$	3.3		μA

(1) Limits -40°C to 125°C apply over the entire junction temperature range for operation. Limits appearing in normal type apply for $T_A = T_J = 25°C$.

6.6 Typical Characteristics



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7 Detailed Description

7.1 Overview

The SM74611 is designed for use as a bypass diode in photovoltaic modules. The SM74611 utilizes a charge pump to drive an N-channel FET to provide a resistive path for the bypass current to flow.

7.2 Functional Block Diagram

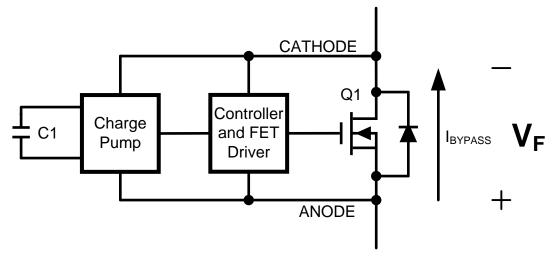


Figure 4. SM74611 Block Diagram

7.3 Feature Description

The operational description is described below. Please refer to Figure 4 and Figure 5.

From t_0 to t_1 :

When cells in the solar panels are shaded, the FET Q1 is off and the bypass current will flow through the body diode of the FET as shown on Figure 4. This current will produce a voltage drop (V_F) across ANODE and CATHODE terminal of the bypass diode. During this time, the charge pump circuitry is active and charging capacitor C1 to a higher voltage.

At t₁:

Once the voltage on the capacitor reaches its predetermined voltage level, the charge pump is disabled and the capacitor voltage is used to drive the FET through the FET driver stage.

From t₁ to t₂ :

When the FET is active, it provides a low resistive path for the bypass current to flow thus minimizing the power dissipation across ANODE and CATHODE. Since the FET is active, the voltage across the ANODE and CATHODE is too low to operate the charge pump. During this time, the stored charge on C1 is used to supply the controller as well as drive the FET.

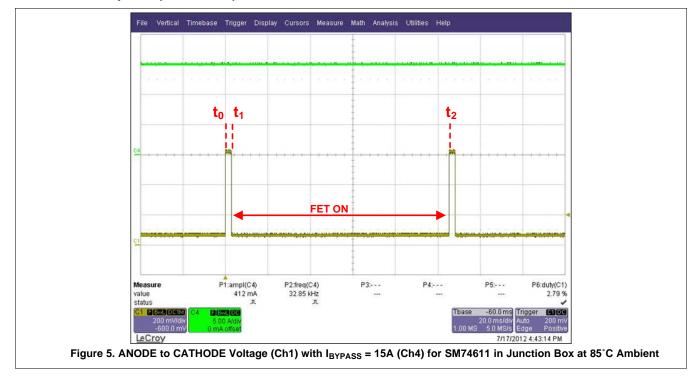
At t₂:

When the voltage on the capacitor C1 reaches its predetermined lower level, the FET driver shuts off the FET. The bypass current will then begin to flow through the body diode of the FET, causing the FET body diode voltage drop of approximately 0.6V to appear across ANODE and CATHODE. The charge pump circuitry is re-activated and begins charging the capacitor C1. This cycle repeats until the shade on the panel is removed and the string current begins to flow through the PV cells instead of the body diode of the FET.

The key factor to minimizing the power dissipation on the device is to keep the FET on at a high duty cycle. The average forward voltage drop will then be reduced to a much lower voltage than for a Schottky or regular P-N junction diode.



Feature Description (continued)





8 Device and Documentation Support

8.1 Trademarks

All trademarks are the property of their respective owners.

8.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

8.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



19-Nov-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SM74611KTTR	ACTIVE	DDPAK/ TO-263	КТТ	3	500	Pb-Free (RoHS Exempt)	CU SN	Level-3-245C-168 HR	-40 to 125	SM74611KTT	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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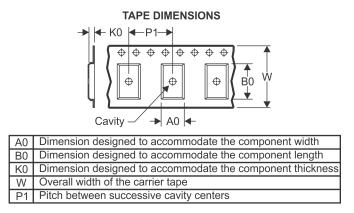
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SM74611KTTR	DDPAK/ TO-263	КТТ	3	500	330.0	24.4	10.6	15.8	4.9	16.0	24.0	Q2

TEXAS INSTRUMENTS

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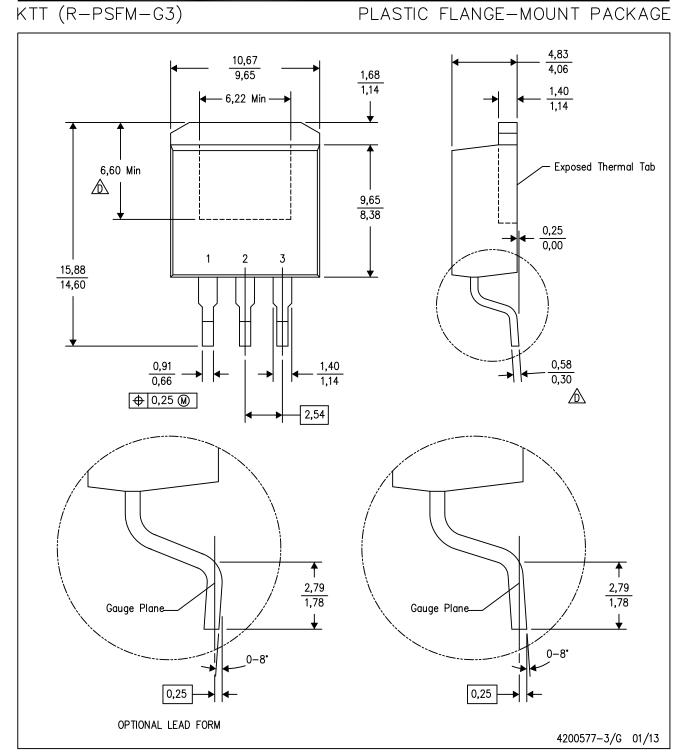
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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SM74611KTTR	DDPAK/TO-263	КТТ	3	500	340.0	340.0	38.0

MECHANICAL DATA



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 (0,13) per side.

⚠️ Falls within JEDEC TO−263 variation AA, except minimum lead thickness and minimum exposed pad length.



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